

Symbol	Parameter		Ratings	Units	
V _{DSS}	Drain-to-Source Voltage		80	V	
V _{GS}	Gate-to-Source Voltage		±20	V	
	Drain Current - Continuous (V _{GS} =10) (Note 1)	T _C =25°C	300	Α	
	Pulsed Drain Current	T _C = 25°C	See Figure 4		
E _{AS}	Single Pulse Avalanche Energy	(Note 2)	820	mJ	
P _D	Power Dissipation		429	W	
	Derate Above 25°C		2.86	W/ ^o C	
T _J , T _{STG}	Operating and Storage Temperature		-55 to + 175	°C	
$R_{\theta JC}$	Thermal Resistance, Junction to Case		0.35	°C/W	
$R_{\theta JA}$	Maximum Thermal Resistance, Junction to Ambient (Note 3)		43	°C/W	

Notes:

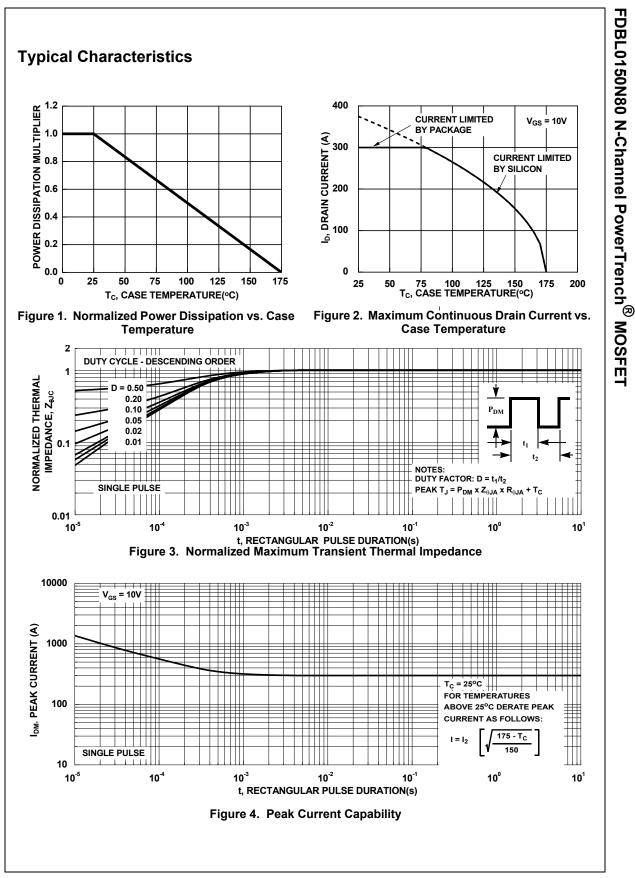
1: Current is limited by bondwire configuration.

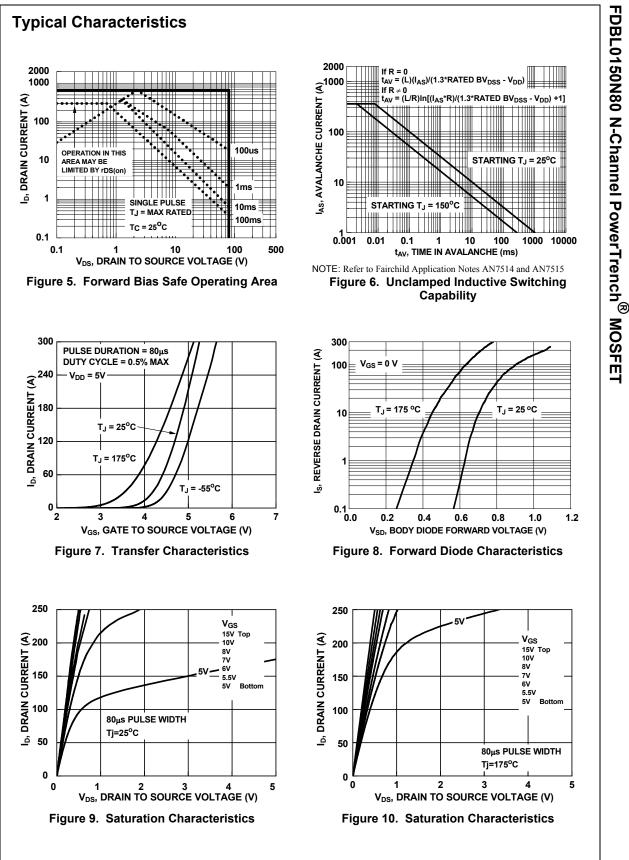
2: Starting T_J = 25°C, L = 0.4mH, I_{AS} = 64A, V_{DD} = 40V during inductor charging and V_{DD} = 0V during time in avalanche. 3: $R_{0,JA}$ is the sum of the junction-to-case and case-to-ambient thermal resistance, where the case thermal reference is defined as the solder moduling surface of the drain pins. $R_{\theta JC}$ is guaranteed by design, while $R_{\theta JA}$ is determined by the board design. The maximum rating presented here is based on mounting on a 1 in² pad of 2oz copper.

Package Marking and Ordering Information

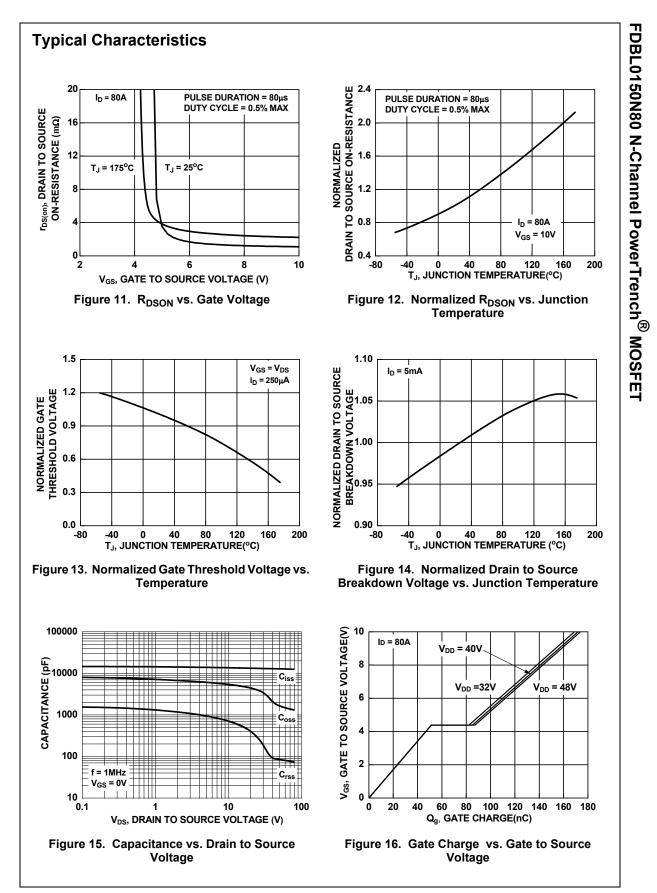
Device Marking	Device	Package			
FDBL0150N80	FDBL0150N80	MO-299A	-	-	-

Symbol	Parameter	Test Conditions		Тур.	Max.	Units
Off Cha	racteristics					
B _{VDSS}	Drain-to-Source Breakdown Voltage	I _D = 250μA, V _{GS} = 0V	80	-	-	V
		$V_{\rm DS}$ =80V, $T_{\rm J}$ =25°C	-	-	1	μA
IDSS	Drain-to-Source Leakage Current	$V_{GS} = 0V$ $T_J = 175^{\circ}C$ (Note 4)	-	-	1	mA
I _{GSS}	Gate-to-Source Leakage Current	V _{GS} = ±20V	-	-	±100	nA
On Cha	racteristics					
V _{GS(th)}	Gate to Source Threshold Voltage	V _{GS} = V _{DS} , I _D = 250μA	2.0	3.0	4.0	V
		$I_D = 80A, T_J = 25^{\circ}C$	-	1.1	1.4	mΩ
R _{DS(on)}	Drain to Source On Resistance	V_{GS} = 10V T_{J} = 175°C (Note 4)	-	2.4	3.1	mΩ
Dynami C _{iss}	c Characteristics			12800	-	pF
C	Output Capacitance	V _{DS} = 25V, V _{GS} = 0V,		1925	_	pF
C _{oss}	Reverse Transfer Capacitance	f = 1MHz f = 1MHz		1323	-	pF
C _{rss} P	Gate Resistance			3.0	4.6	ρι Ω
R _g	Total Gate Charge at 10V			172	188	nC
Q _{g(ToT)} Q _{g(th)}	Threshold Gate Charge	$V_{GS} = 0 \text{ to } 10V$ $V_{DD} = 64V$ $V_{GS} = 0 \text{ to } 2V$ $I_D = 80A$		23	27	nC
• • • •	Gate-to-Source Gate Charge	VGS 01021 ID - 00A		51	-	nC
Q _{gs} Q _{gd}	Gate-to-Drain "Miller" Charge			34	-	nC
Switchi	ng Characteristics			1		
t _{on}	Turn-On Time		-	-	128	ns
t _{d(on)}	Turn-On Delay		-	42	-	ns
t _r	Rise Time	$V_{DD} = 40V, I_D = 80A,$	-	73	-	ns
t _{d(off)}	Turn-Off Delay	V _{GS} = 10V, R _{GEN} = 6Ω	-	87	-	ns
t _f	Fall Time		-	48	-	ns
t _{off}	Turn-Off Time		-	-	193	ns
Drain-S	ource Diode Characteristics					
V _{SD}	Source-to-Drain Diode Voltage	I _{SD} =80A, V _{GS} = 0V	-	-	1.25	V
		I_{SD} = 40A, V_{GS} = 0V	-	-	1.2	V
t _{rr}	Reverse-Recovery Time	$I_{F} = 80A, dI_{SD}/dt = 100A/\mu s,$	-	117	136	ns
Q _{rr}	Reverse-Recovery Charge	V _{DD} =64V		205	269	nC

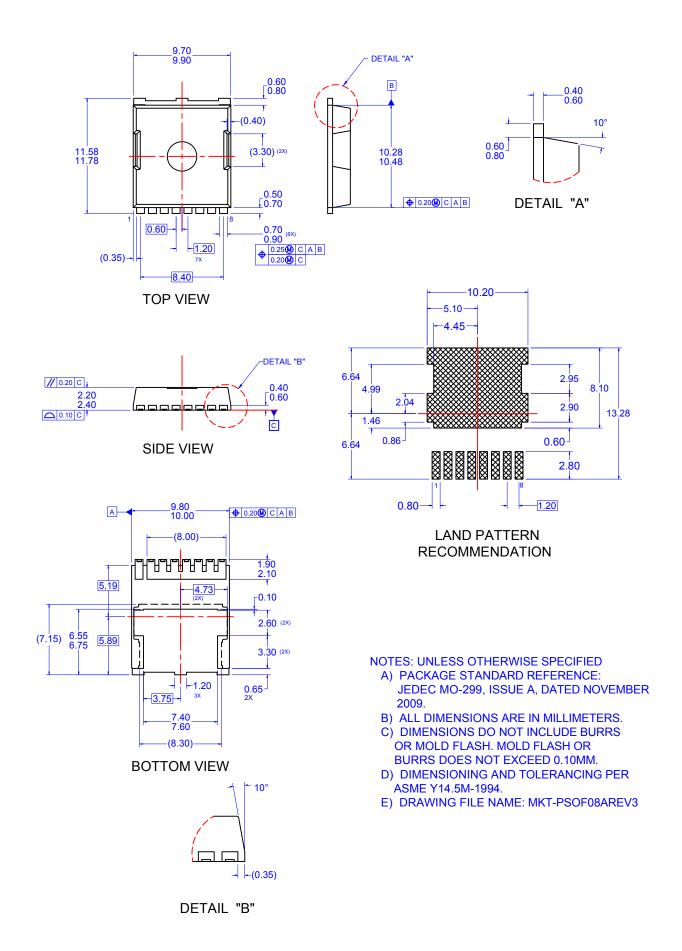




FDBL0150N80 Rev.1.2



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